

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants : Gabriele Barlocchi et al.
Application No. : 10/667,113
Filed : September 18, 2003
For : METHOD FOR FORMING HORIZONTAL BURIED CHANNELS OR
CAVITIES IN WAFERS OF MONOCRYSTALLINE
SEMICONDUCTOR MATERIAL

Examiner : Fazli Erdem
Art Unit : 2826
Docket No. : 854063.552D1
Date : October 19, 2007

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

SUPPLEMENTAL AMENDMENT

Commissioner for Patents:

Please amend the application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 6 of this paper.